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PATENT ABSTRACTS OF JAPAN

(21) Application number: **05291013**

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(71) Applicant: FUJITSU LTD

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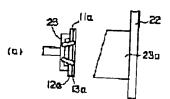
(74) Representative:

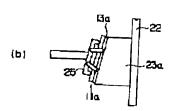
(54) PARTICLE
REMOVING
METHOD AND
SEMICONDUCTOR
PRODUCTION
SYSTEM HAVING
PARTICLE
REMOVING MEANS

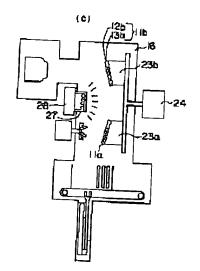
(57) Abstract:

PURPOSE: To provide a method for removing particles from a semiconductor production system or from the surface of a semiconductor substrate or a reticle more easily and positively with no adverse effect.

CONSTITUTION: Particle eliminators 11a, 11b are bonded, at the adhesive layers 13a, 13b thereof, to bases 23a, 23b for mounting a substrate. Subsequently, the





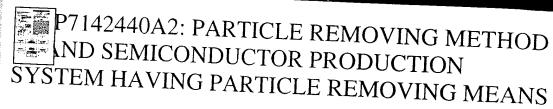


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Inventor(s):

SUGINO SHIGEYUKI MORI HARUHISA **FUJIMURA SHUZO OGAWA HIROTERU** SHIRAKAWA YOSHIMI **INABA MICHIKO** ISHIKAWA KENJI KANEDA HIROSHI

Applicant(s):

FUJITSU LTD

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Issued/Filed Dates: June 2, 1995 / Nov. 19, 1993

Application Number: IPC Class:

JP1993000291013

H01L 21/304; B08B 7/00;

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Other Abstract Info: Foreign

DERABS G95-235223 DERG95-235223

References: Powered by **DBO**

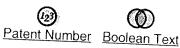
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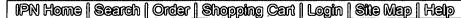






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P7142440A2: PARTICLE REMOVING METHOD AND SEMICONDUCTOR PRODUCTION SYSTEM HAVING PARTICLE REMOVING MEANS

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inventor(s):

SUGINO SHIGEYUKI MORI HARUHISA FUJIMURA SHUZO OGAWA HIROTERU SHIRAKAWA YOSHIMI INABA MICHIKO ISHIKAWA KENJI KANEDA HIROSHI

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